Thyristor Semiconductor Device - Page 1 of 1



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### Inclosure Material:

Ceramic

# Overall Length:

Between 0.560 inches and 0.650 inches

## **Overall Height:**

Between 0.140 inches and 0.190 inches

### **Overall Width:**

Between 0.380 inches and 0.420 inches

### **End Application:**

8emory s. Land class as; ticonderoga class cg (47); nimitz class cvn; los angeles class ssn (688); tarawa class lha; forrestal class cv; spruance class dd (963); general purpose electronic test equipment gpete; kidd class dd; arleigh burke class ddg

### Mounting Facility Quantity:

1

### **Mounting Method:**

Unthreaded hole

### Features Provided:

Hermetically sealed case

## **Criticality Code Justification:**

Feat

### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

50.0 repetitive peak off-state voltage and 1.7 on-state voltage, dc

## **Current Rating Per Characteristic:**

32.00 amperes forward current, total rms nanoamperes

## Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius case

### **Special Features:**

Weapon system essential

### **Terminal Type And Quantity:**

3 uninsulated wire lead

### **Specification Data:**

80131-release6437 professional/industrial association specification

### Shelf Life:

N/a

### Unit Of Measure:

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### Demilitarization:

No

## Fiig:

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